V_{CE} = 600 V, I_C = 37 A
Trench IGBT with Fast Recovery Diode

MGD623S

Data Sheet

Description

The MGD623S is 600 V trench IGBT. Sanken original trench structure decreases gate capacitance, and achieves high speed switching and switching loss reduction. Thus, the IGBT can improve the efficiency of your circuit.

Features

- Low Saturation Voltage
- High Speed Switching
- With Integrated Low V_F Fast Recovery Diode
- Bare Lead Frame: Pb-free (RoHS Compliant)

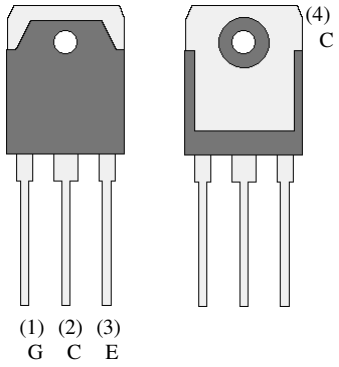
- V_{CE} ---------- 600 V
- I_C (T_C = 100 °C) ---------- 37 A
- $V_{CE(sat)}$ ---------- 1.8 V typ.
- t_f (T_J = 25 °C) ---------- 120 ns typ.
- V_F ---------- 1.2 V typ.

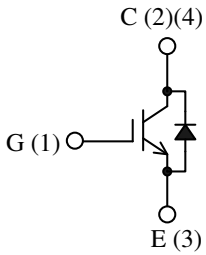
Applications

- Microwave Oven
- IH Cooker
- Inverter Circuit

Package

TO3P-3L





Not to scale

Absolute Maximum Ratings

Unless otherwise specified, T_A = 25 °C.

Parameter	Symbol	Conditions	Rating	Unit	Remarks
Collector to Emitter Voltage	V_{CE}		600	V	
Gate to Emitter Voltage	V_{GE}		±30	V	
Continuous Collector Current	I_C	T_C = 25 °C	50	A	
		T_C = 100 °C	37	A	
Pulsed Collector Current	$I_{C(PULSE)}$	$P_W \leq 1$ ms, duty cycle ≤ 1%	100	A	
Diode Continuous Forward Current	I_F	T_C = 25 °C	30	A	
Diode Pulsed Forward Current	$I_{F(PULSE)}$	$P_W \leq 1$ ms, duty cycle ≤ 1%	60	A	
Maximum Collector to Emitter dv/dt	dv/dt	$T_C \leq 125$ °C, see Figure 1	5	V/ns	
Power Dissipation	P_D	T_C = 25 °C	150	W	
Operating Junction Temperature	T_J		150	°C	
Storage Temperature	T_{STG}		−55 to 150	°C	

Thermal Characteristics

Unless otherwise specified, T_A = 25 °C.

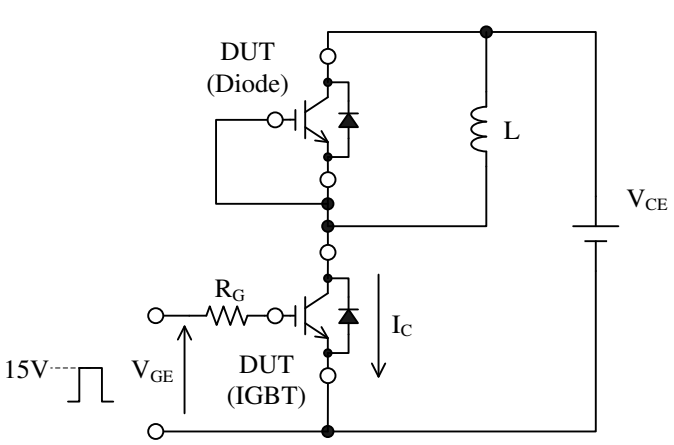
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	Remarks
Thermal Resistance of IGBT (Junction to Case)	$R_{\theta JC(IGBT)}$		—	—	0.833	°C/W	
Thermal Resistance of Diode (Junction to Case)	$R_{\theta JC(Di)}$		—	—	1.67	°C/W	

Electrical Characteristics

Unless otherwise specified, T_A = 25 °C.

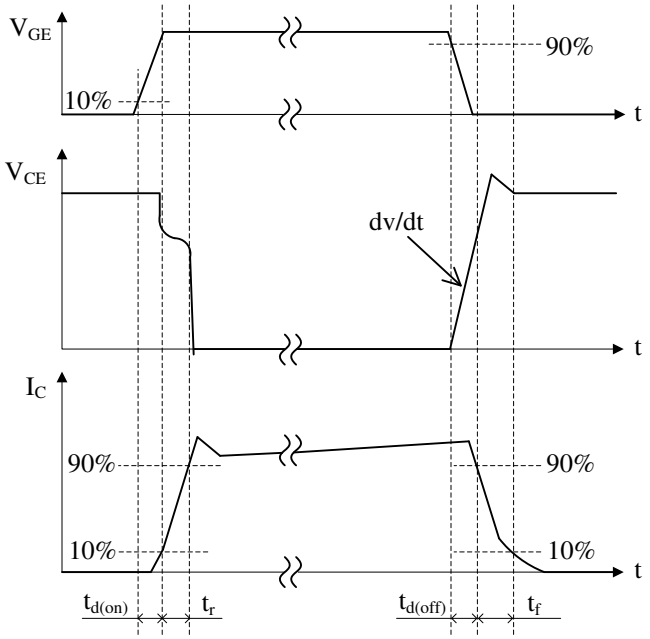
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector to Emitter Breakdown Voltage	$V_{(BR)CES}$	I_C = 100 µA, V_{GE} = 0 V	600	—	—	V
Collector to Emitter Leakage Current	I_{CES}	V_{CE} = 600 V, V_{GE} = 0 V	—	—	100	µA
Gate to Emitter Leakage Current	I_{GES}	V_{GE} = ±30 V	—	—	±500	nA
Gate Threshold Voltage	$V_{GE(TH)}$	V_{CE} = 10 V, I_C = 1 mA	3	4.5	6	V
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE} = 15 V, I_C = 50 A	—	1.8	2.4	V
Input Capacitance	C_{ies}	V_{CE} = 20 V, V_{GE} = 0 V, f = 1.0 MHz	—	2500	—	pF
Output Capacitance	C_{oes}		—	150	—	
Reverse Transfer Capacitance	C_{res}		—	80	—	
Total Gate Charge	Q_G	V_{CE} = 300 V, I_C = 50 A, V_{GE} = 15 V	—	65	—	nC
Gate to Emitter Charge	Q_{GE}		—	20	—	
Gate to Collector Charge	Q_{GC}		—	20	—	
Turn-on Delay Time	$t_{d(on)}$	T_J = 25 °C, see Figure 1	—	75	—	ns
Rise Time	t_r		—	100	—	
Turn-off Delay Time	$t_{d(off)}$		—	300	—	
Fall Time	t_f		—	120	—	
Turn-on Delay Time	$t_{d(on)}$	T_J = 125 °C, see Figure 1	—	75	—	ns
Rise Time	t_r		—	100	—	
Turn-off Delay Time	$t_{d(off)}$		—	300	—	
Fall Time	t_f		—	200	—	
Emitter to Collector Diode Forward Voltage	V_F	I_F = 30 A	—	1.2	1.6	V
Emitter to Collector Diode Reverse Recovery Time	t_{rr}	I_F = 30 A, di/dt = 100 A/µs	—	300	—	ns

Test Circuits and Waveforms



Conditions:
V_{CE} = 300 V
I_C = 50 A
V_{GE} = 15 V
R_G = 39 Ω
L = 100 μH

(a) Test Circuit



(b) Waveform

Figure 1. Test Circuits and Waveforms of dv/dt and Switching Time

Rating and Characteristic Curves

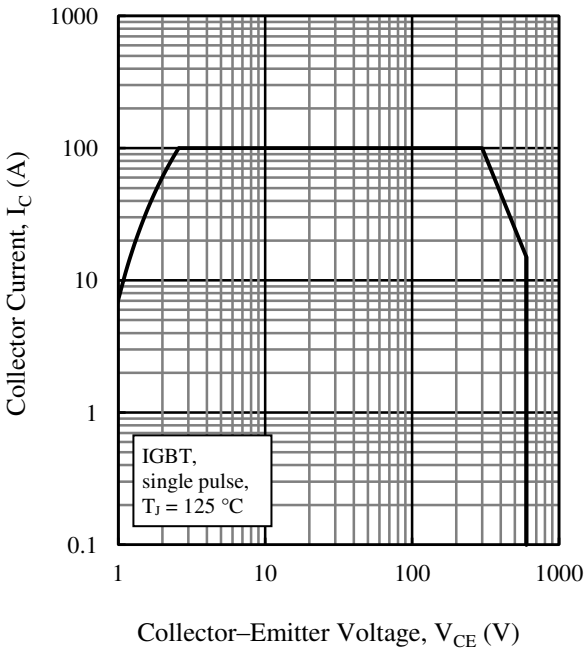


Figure 2. IGBT Reverse Bias Safe Operating Area

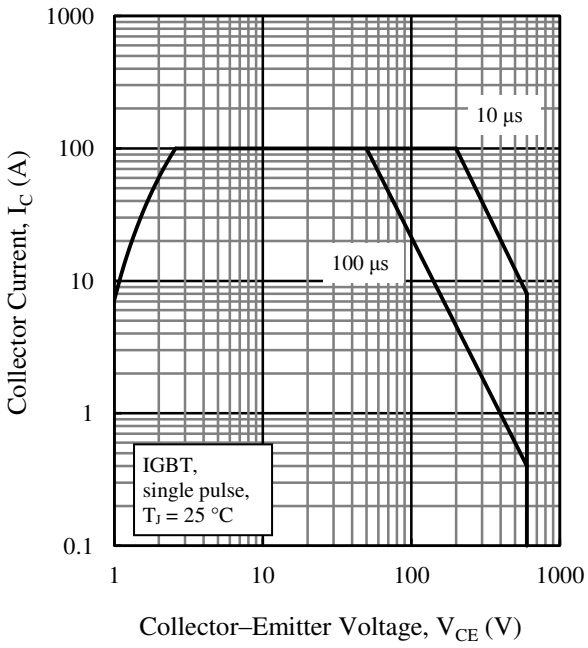


Figure 3. IGBT Safe Operating Area

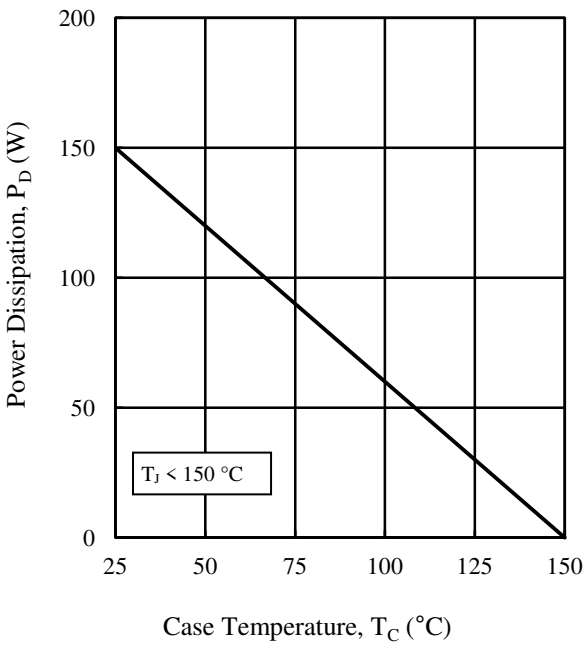


Figure 4. Power Dissipation vs. Case Temperature

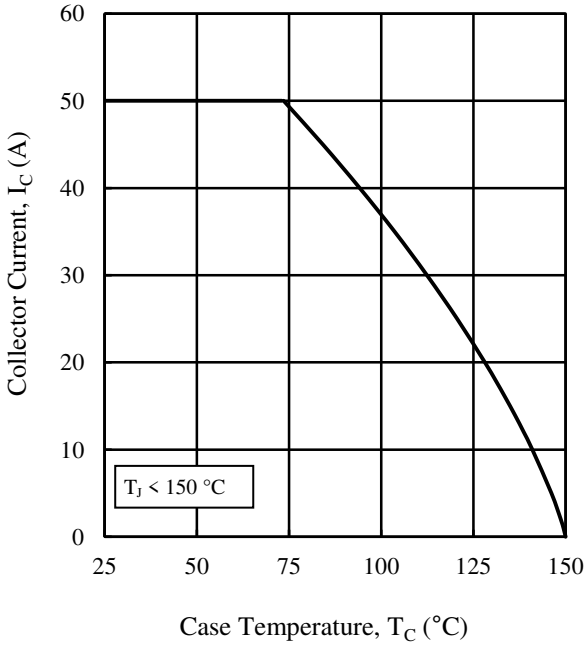


Figure 5. Collector Current vs. Case Temperature

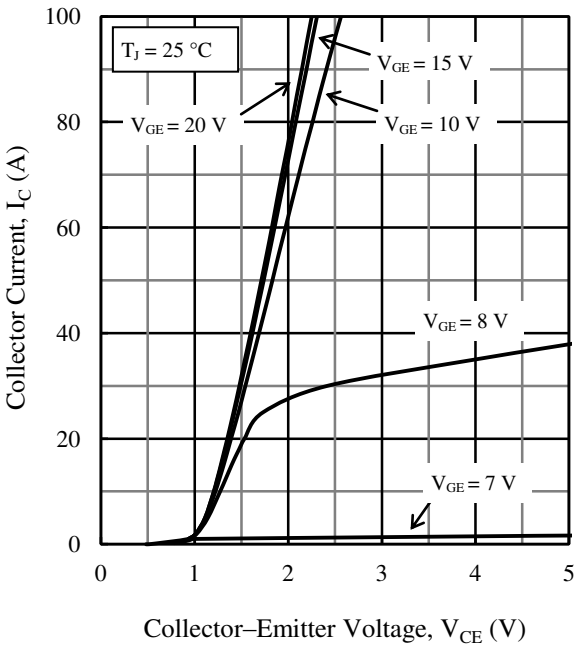


Figure 6. Output Characteristics (T_J = 25 °C)

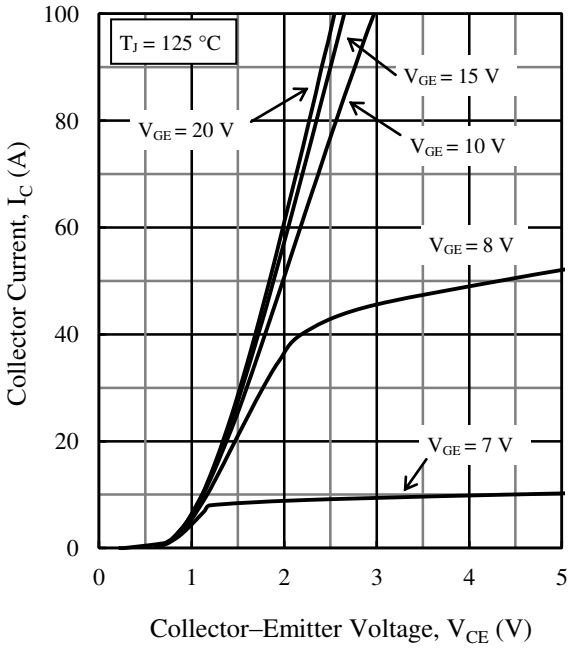


Figure 7. Output Characteristics (T_J = 125 °C)

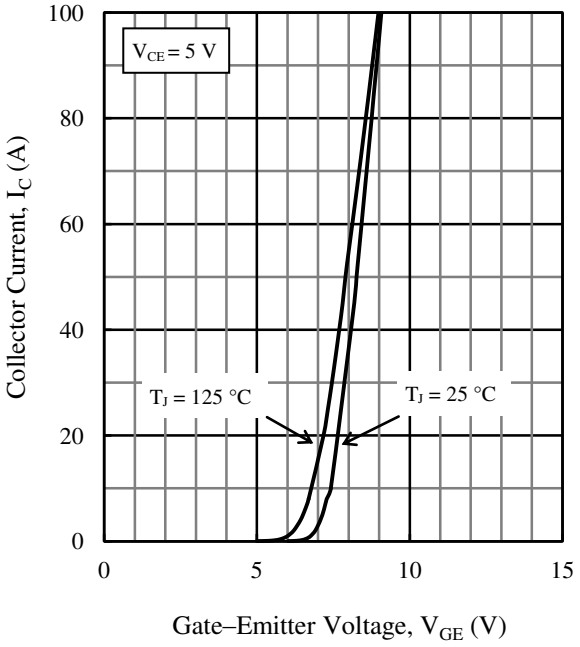


Figure 8. Transfer Characteristics

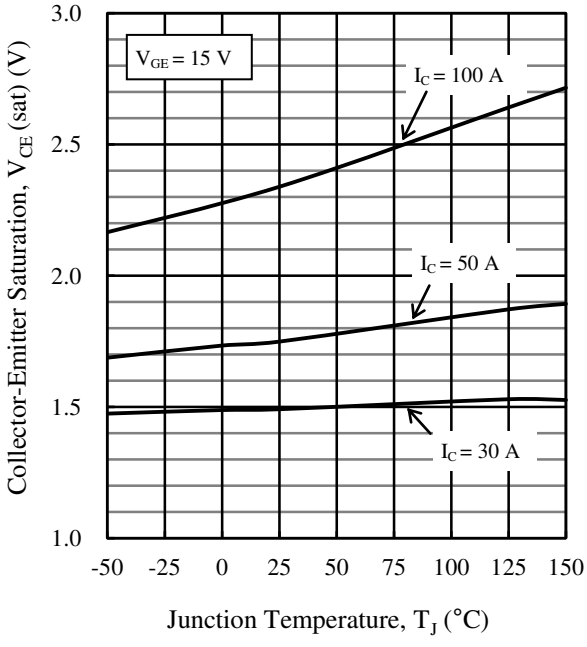


Figure 9. Saturation Voltage vs. Junction Temperature

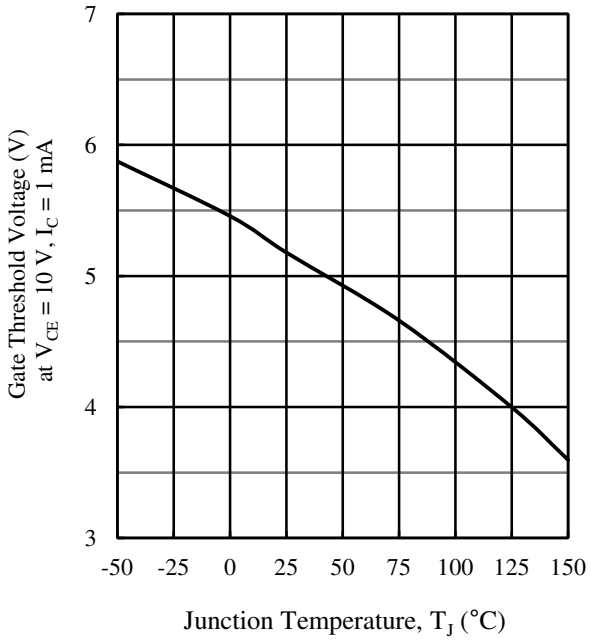


Figure 10. Gate Threshold Voltage vs. Junction Temperature

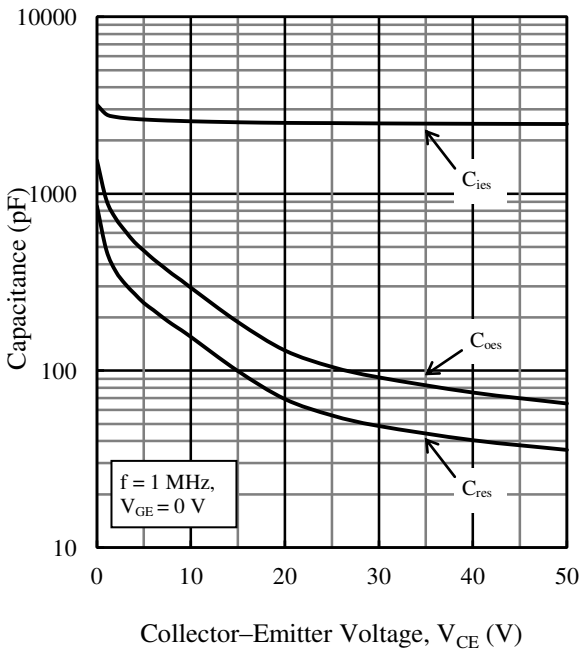


Figure 11. Capacitance Characteristics

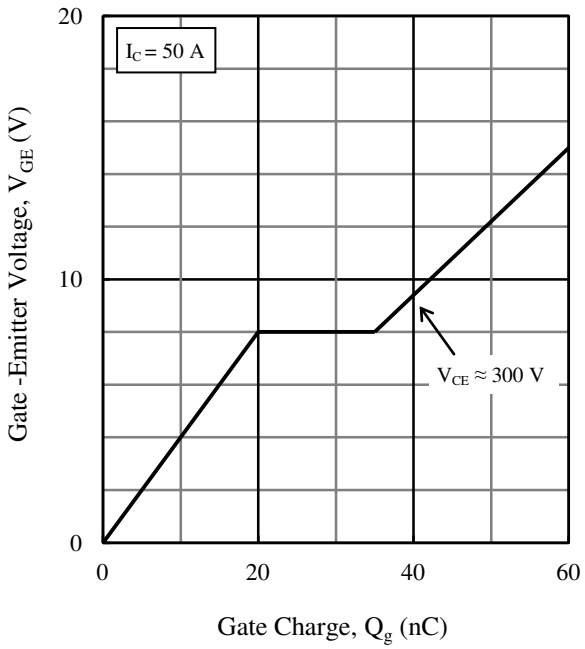


Figure 12. Typical Gate Charge

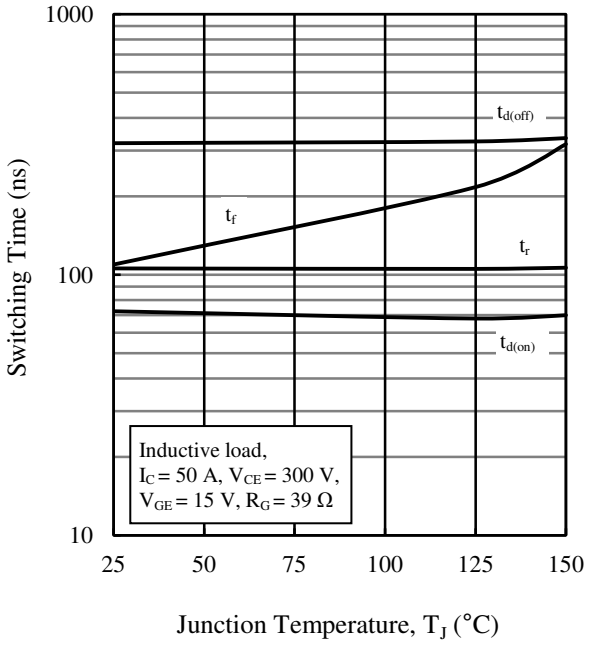


Figure 13. Switching Time vs. Junction Temperature

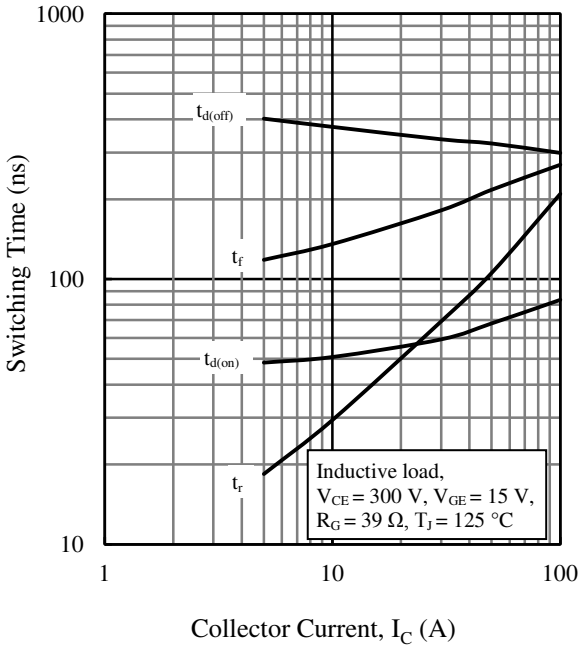


Figure 14. Switching Time vs. Collector Current

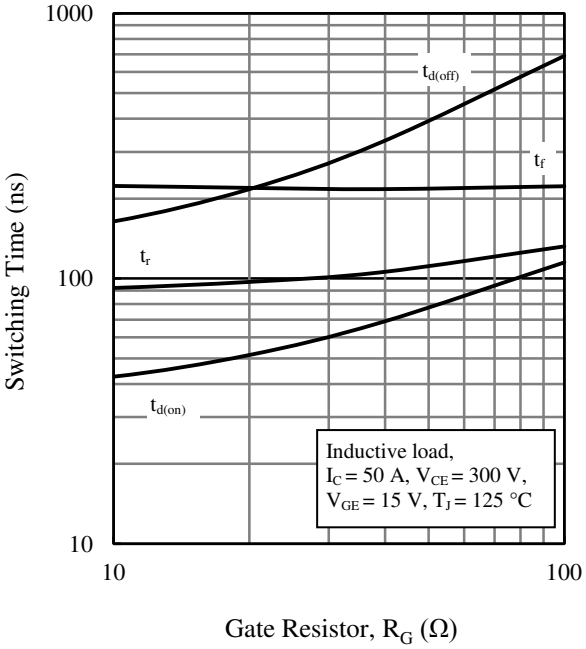


Figure 15. Switching Time vs. Gate Resistor

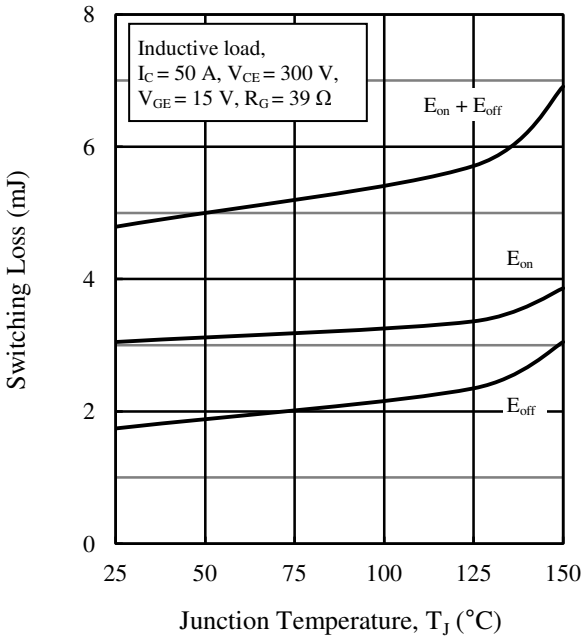


Figure 16. Switching Loss vs. Junction Temperature

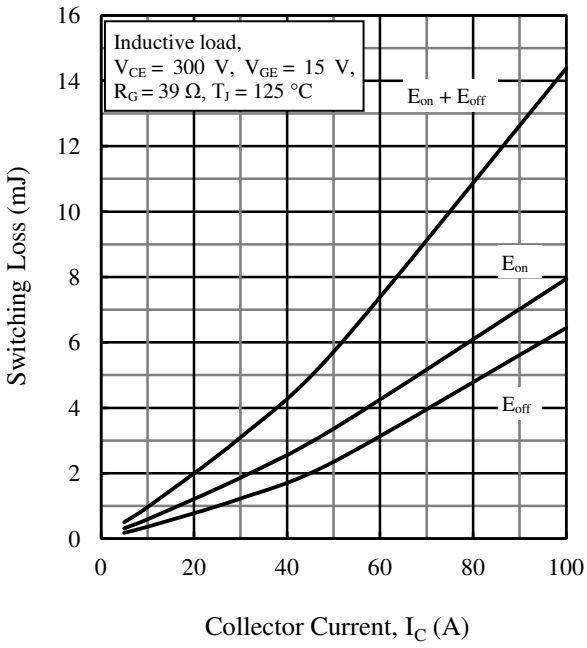


Figure 17. Switching Loss vs. Collector Current

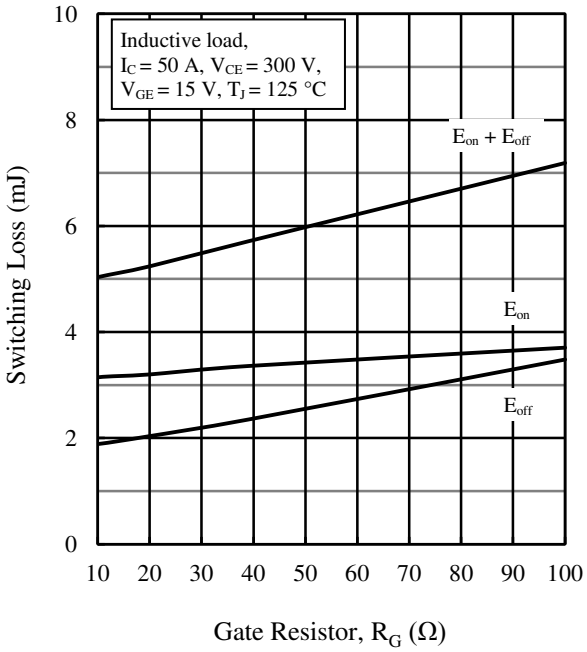


Figure 18. Switching Loss vs. Gate Resistor

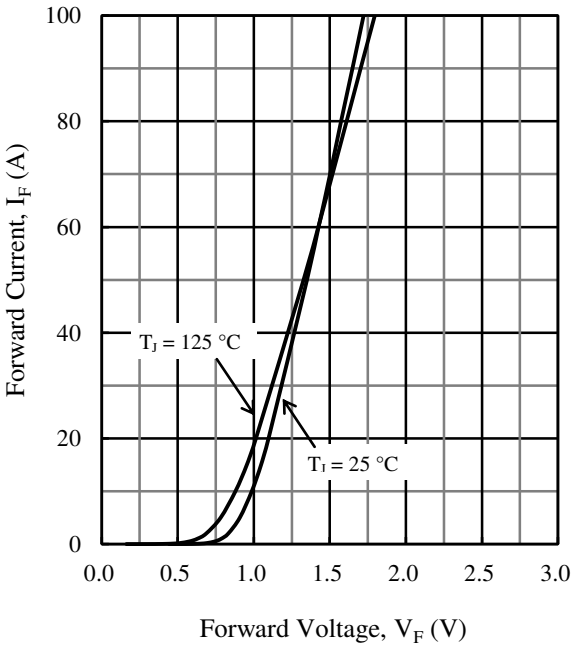


Figure 19. Diode Forward Characteristics

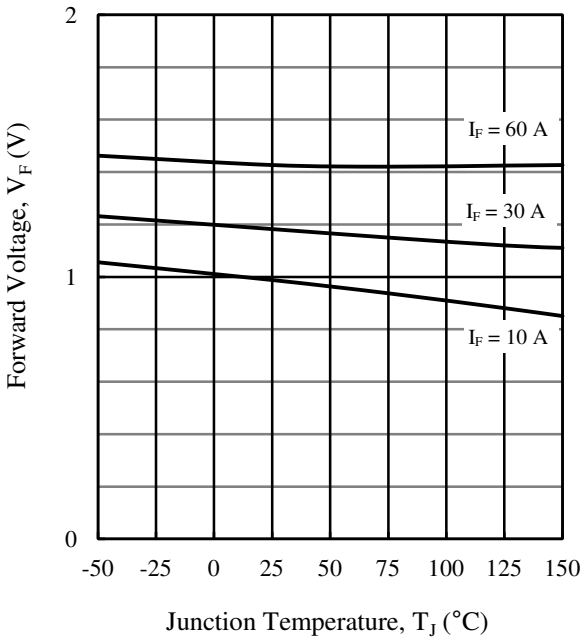


Figure 20. Diode Forward Voltage vs. Junction Temperature

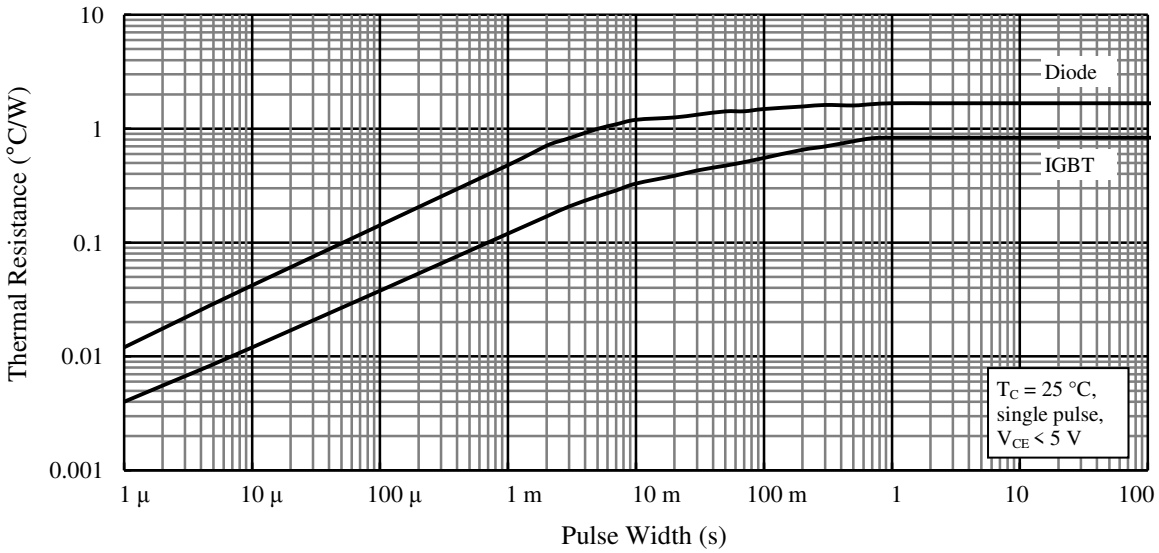
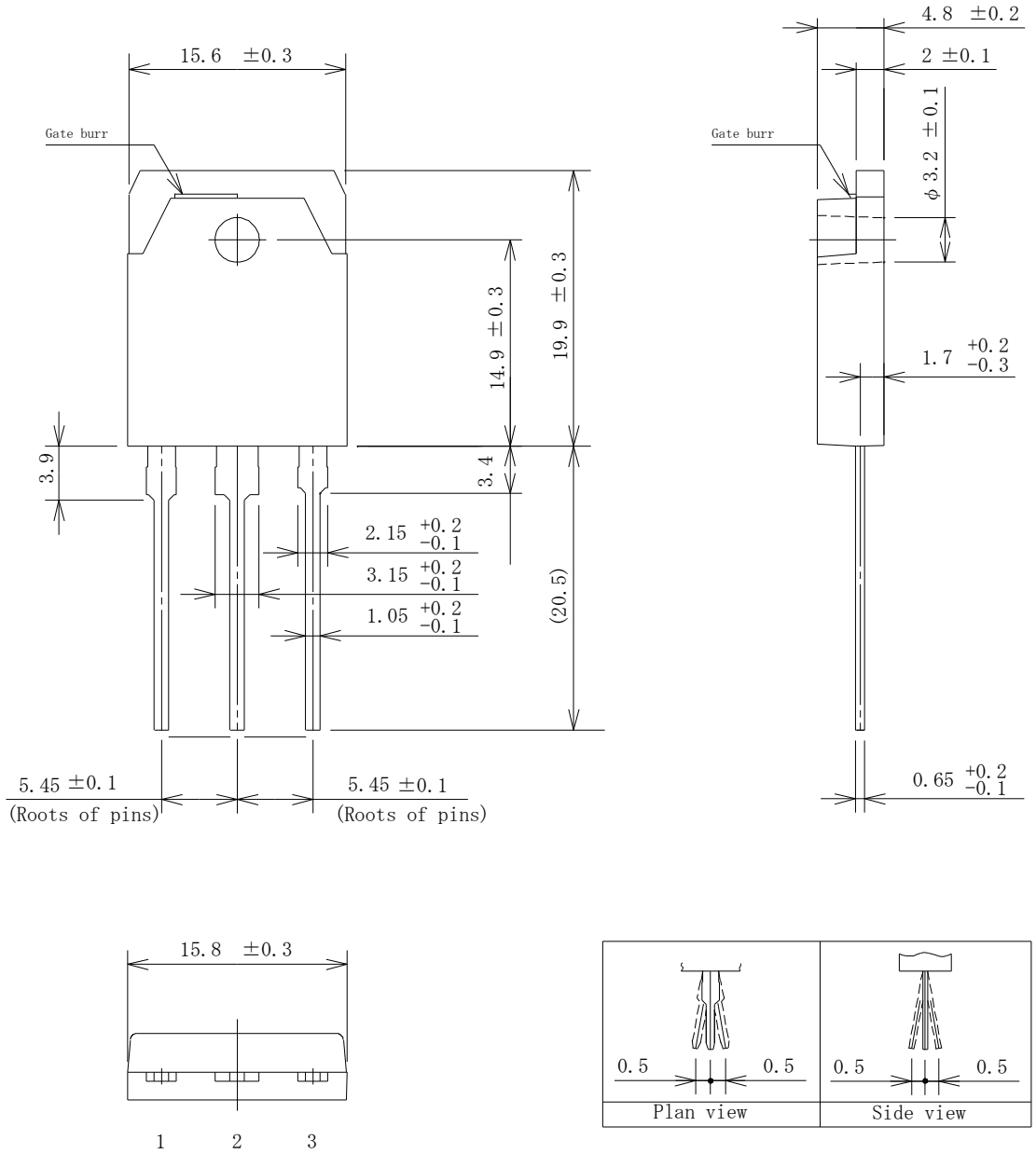


Figure 21. Transient Thermal Resistance

Physical Dimension

● **TO3P-3L**



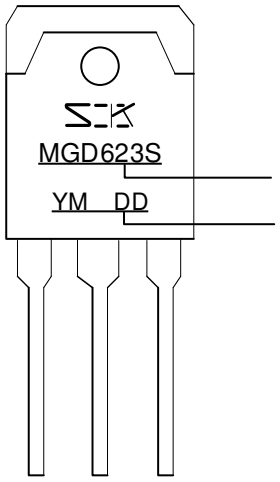
NOTES:

- Dimensions in millimeters
- Maximum gate burr height is 0.3 mm
- Bare lead frame: Pb-free (RoHS compliant)
- When soldering the products, be sure to minimize the working time within the following limits:

  Flow: 260 ± 5 °C / 10 ± 1 s, 2 times
  Soldering iron: 380 ± 10 °C / 3.5 ± 0.5 s, 1 time (Soldering should be at a distance of at least 1.5 mm from the body of the product.)

- Recommended screw torque: 0.686 N·m to 0.882 N·m (7 kgf·cm to 9 kgf·cm)

Marking Diagram



Part Number

Lot Number

Y is the last digit of the year of manufacture (0 to 9)

M is the month of the year (1 to 9, O, N, or D)

DD is the date of the month (01 to 31)

Important Notes

- All data, illustrations, graphs, tables and any other information included in this document (the "Information") as to Sanken's products listed herein (the "Sanken Products") are current as of the date this document is issued. The Information is subject to any change without notice due to improvement of the Sanken Products, etc. Please make sure to confirm with a Sanken sales representative that the contents set forth in this document reflect the latest revisions before use.
- The Sanken Products are intended for use as components of general purpose electronic equipment or apparatus (such as home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). Prior to use of the Sanken Products, please put your signature, or affix your name and seal, on the specification documents of the Sanken Products and return them to Sanken. When considering use of the Sanken Products for any applications that require higher reliability (such as transportation equipment and its control systems, traffic signal control systems or equipment, disaster/crime alarm systems, various safety devices, etc.), you must contact a Sanken sales representative to discuss the suitability of such use and put your signature, or affix your name and seal, on the specification documents of the Sanken Products and return them to Sanken, prior to the use of the Sanken Products. The Sanken Products are not intended for use in any applications that require extremely high reliability such as: aerospace equipment; nuclear power control systems; and medical equipment or systems, whose failure or malfunction may result in death or serious injury to people, i.e., medical devices in Class III or a higher class as defined by relevant laws of Japan (collectively, the "Specific Applications"). Sanken assumes no liability or responsibility whatsoever for any and all damages and losses that may be suffered by you, users or any third party, resulting from the use of the Sanken Products in the Specific Applications or in manner not in compliance with the instructions set forth herein.
- In the event of using the Sanken Products by either (i) combining other products or materials or both therewith or (ii) physically, chemically or otherwise processing or treating or both the same, you must duly consider all possible risks that may result from all such uses in advance and proceed therewith at your own responsibility.
- Although Sanken is making efforts to enhance the quality and reliability of its products, it is impossible to completely avoid the occurrence of any failure or defect or both in semiconductor products at a certain rate. You must take, at your own responsibility, preventative measures including using a sufficient safety design and confirming safety of any equipment or systems in/for which the Sanken Products are used, upon due consideration of a failure occurrence rate and derating, etc., in order not to cause any human injury or death, fire accident or social harm which may result from any failure or malfunction of the Sanken Products. Please refer to the relevant specification documents and Sanken's official website in relation to derating.
- No anti-radioactive ray design has been adopted for the Sanken Products.
- The circuit constant, operation examples, circuit examples, pattern layout examples, design examples, recommended examples, all information and evaluation results based thereon, etc., described in this document are presented for the sole purpose of reference of use of the Sanken Products.
- Sanken assumes no responsibility whatsoever for any and all damages and losses that may be suffered by you, users or any third party, or any possible infringement of any and all property rights including intellectual property rights and any other rights of you, users or any third party, resulting from the Information.
- No information in this document can be transcribed or copied or both without Sanken's prior written consent.
- Regarding the Information, no license, express, implied or otherwise, is granted hereby under any intellectual property rights and any other rights of Sanken.
- Unless otherwise agreed in writing between Sanken and you, Sanken makes no warranty of any kind, whether express or implied, including, without limitation, any warranty (i) as to the quality or performance of the Sanken Products (such as implied warranty of merchantability, or implied warranty of fitness for a particular purpose or special environment), (ii) that any Sanken Product is delivered free of claims of third parties by way of infringement or the like, (iii) that may arise from course of performance, course of dealing or usage of trade, and (iv) as to the Information (including its accuracy, usefulness, or reliability).
- In the event of using the Sanken Products, you must use the same after carefully examining all applicable environmental laws and regulations that regulate the inclusion or use or both of any particular controlled substances, including, but not limited to, the EU RoHS Directive, so as to be in strict compliance with such applicable laws and regulations.
- You must not use the Sanken Products or the Information for the purpose of any military applications or use, including but not limited to the development of weapons of mass destruction. In the event of exporting the Sanken Products or the Information, or providing them for non-residents, you must comply with all applicable export control laws and regulations in each country including the U.S. Export Administration Regulations (EAR) and the Foreign Exchange and Foreign Trade Act of Japan, and follow the procedures required by such applicable laws and regulations.
- Sanken assumes no responsibility for any troubles, which may occur during the transportation of the Sanken Products including the falling thereof, out of Sanken's distribution network.
- Although Sanken has prepared this document with its due care to pursue the accuracy thereof, Sanken does not warrant that it is error free and Sanken assumes no liability whatsoever for any and all damages and losses which may be suffered by you resulting from any possible errors or omissions in connection with the Information.
- Please refer to our official website in relation to general instructions and directions for using the Sanken Products, and refer to the relevant specification documents in relation to particular precautions when using the Sanken Products.
- All rights and title in and to any specific trademark or tradename belong to Sanken and such original right holder(s).

DSGN-CEZ-16003